

PHEMT GaAs IC High Linearity 3 V Control SPDT Switch 0.1–2.5 GHz



AS193-73

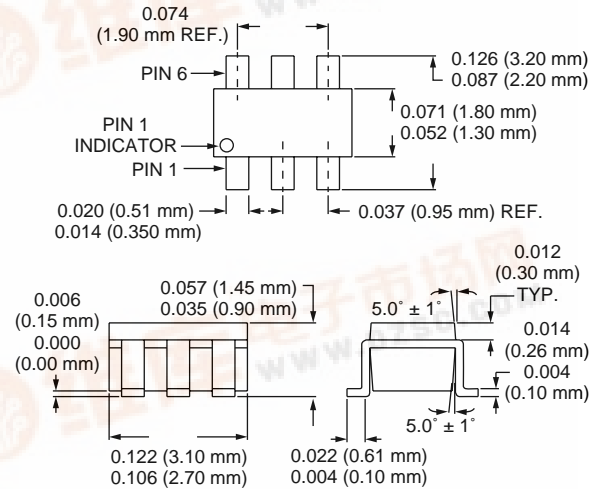
Features

- +2.5 to +5 V Linear Operation
- Harmonics H₂, H₃ > 65 dBc @ P_{IN} = 34.5 dBm
- Low Insertion Loss (0.35 dB @ 0.9 GHz)
- High Isolation (24 dB @ 0.9 GHz)
- Ultra Miniature SOT-6 Package
- PHEMT Process

Description

The AS193-73 is a PHEMT GaAs FET IC high linearity SPDT switch in a SOT-6 plastic package. This switch has been designed for use where extremely high linearity, low control voltage, high isolation, low insertion loss and ultra miniature package size are required. It can be controlled with positive, negative or a combination of both voltages. Some standard implementations include antenna changeover, T/R and diversity switching over 3 W. The

SOT-6



AS193-73 switch can be used in many analog and digital wireless communication systems including cellular, GSM and UMTS applications.

Electrical Specifications at 25°C (0, +3 V)

Parameter ¹	Frequency	Min.	Typ.	Max.	Unit
Insertion Loss ²	0.1–0.5 GHz		0.30	0.4	dB
	0.5–1.0 GHz		0.35	0.5	dB
	1.0–2.0 GHz		0.45	0.6	dB
	2.0–2.5 GHz		0.55	0.7	dB
Isolation	0.1–0.5 GHz	28	30		dB
	0.5–1.0 GHz	22	24		dB
	1.0–2.0 GHz	17	19		dB
	2.0–2.5 GHz	15	17		dB
VSWR ³	0.1–1.0 GHz		1.2:1		dB
	1.0–2.5 GHz		1.3:1		dB

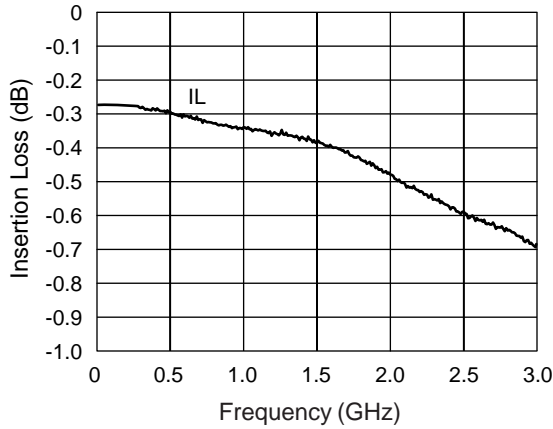
Operating Characteristics at 25°C (0, +3 V)

Parameter	Condition	Frequency	Min.	Typ.	Max.	Unit
Switching Characteristics ⁴	Rise, Fall (10/90% or 90/10% RF)			60		ns
	On, Off (50% CTL to 90/10% RF)			100		ns
	Video Feedthru			50		mV
Input Power for -0.1 dB Compression	0/+3 V	0.9 GHz		+37		dBm
Harmonics H ₂ , H ₃	P _{IN} = 34.5 dBm	0.9 GHz		+65		dBc
Control Voltages	V _{Low} = 0 to 0.2 V @ 20 μA Max. V _{High} = +2.5 V @ 100 μA Max. to +5 V @ 200 μA Max.					

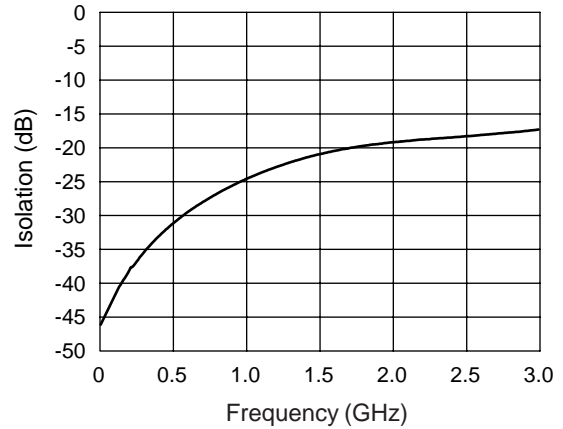
1. All measurements made in a 50 Ω system, unless otherwise specified.
2. Insertion loss changes by 0.003 dB/°C.

3. Insertion loss state.
4. Video feedthru measured with 1 ns risetime pulse and 500 MHz bandwidth.

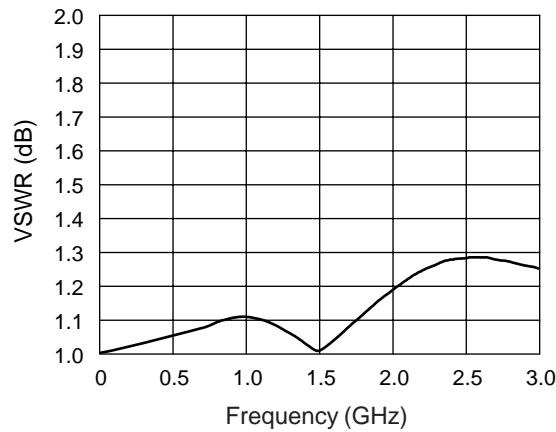
Typical Performance Data



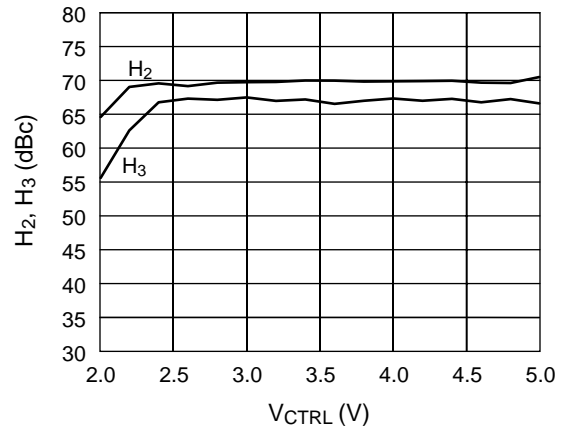
Insertion Loss vs. Frequency



Isolation vs. Frequency



VSWR vs. Frequency



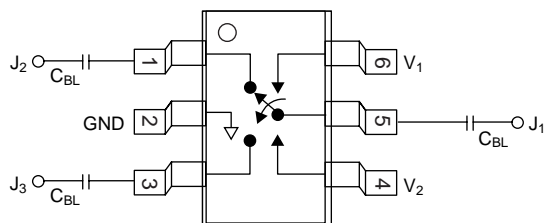
AS193-73 Harmonics vs. Control Voltage
 $P_{IN} = 34.5 \text{ dBm}$, 900 MHz, GSM Pulsed

Truth Table

V_1	V_2	J_1-J_2	J_1-J_3
0	V_{High}	Isolation	Insertion Loss
V_{High}	0	Insertion Loss	Isolation

$V_{High} = +2.5 \text{ to } +5 \text{ V}$.

Pin Out



DC blocking capacitors (C_{BL}) must be supplied externally.
 $C_{BL} = 100 \text{ pF}$ for operating frequency $>500 \text{ MHz}$.

Absolute Maximum Ratings

Characteristic	Value
RF Input Power	6 W Max. $> 900 \text{ MHz}$, 0/+5 V Control
Control Voltage	-0.2 V, +8 V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C
θ_{JC}	25°C/W